CEL

GaAs INTEGRATED CIRCUIT

μPG2406T6R

0.01 to 3.0 GHz SPDT SWITCH

DESCRIPTION

The μPG2406T6R is a GaAs MMIC for L, S-band SPDT (Single Pole Double Throw) switch which were designed for mobile phone and another L, S-band application.

This device can operate 2 control switching by control voltage 1.8 to 3.3 V. This device can operate frequency from 0.01 to 3.0 GHz, having the low insertion loss and high isolation.

This device is housed in a 6-pin plastic TSSON (Thin Shrink Small Out-line Non-leaded) (T6R) package. And this package is able to high-density surface mounting.

FEATURES

- Switch control voltage : $V_{cont\ (H)}$ = 1.8 to 3.3 V (2.7 V TYP.)
  : $V_{cont\ (L)}$ = −0.2 to +0.2 V (0 V TYP.)
- Low insertion loss : L_{ins} = 0.40 dB TYP. @ f = 1.0 GHz, $V_{cont\ (H)}$ = 2.7 V, $V_{cont\ (L)}$ = 0 V
  : L_{ins} = 0.47 dB TYP. @ f = 2.5 GHz, $V_{cont\ (H)}$ = 2.7 V, $V_{cont\ (L)}$ = 0 V
- High isolation : ISL = 27 dB TYP. @ f = 1.0 GHz, $V_{cont\ (H)}$ = 2.7 V, $V_{cont\ (L)}$ = 0 V
  : ISL = 17 dB TYP. @ f = 2.5 GHz, $V_{cont\ (H)}$ = 2.7 V, $V_{cont\ (L)}$ = 0 V
- Handling power : $P_{in\ (0.1\ dB)}$ = +29.0 dBm TYP. @ f = 2.0/2.5 GHz, $V_{cont\ (H)}$ = 2.7 V, $V_{cont\ (L)}$ = 0 V
  : $P_{in\ (1\ dB)}$ = +30.5 dBm TYP. @ f = 0.5 to 3.0 GHz, $V_{cont\ (H)}$ = 2.7 V, $V_{cont\ (L)}$ = 0 V
- High-density surface mounting : 6-pin plastic TSSON (T6R) package (1.0 × 1.0 × 0.37 mm)

APPLICATIONS

- L, S-band digital cellular or cordless telephone
- W-LAN, WLL and Bluetooth™ etc.

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Supplying Form
μPG2406T6R-E2	μPG2406T6R-E2-A	6-pin plastic TSSON (T6R) (Pb-Free)	G9	• Embossed tape 8 mm wide • Pin 1, 6 face the perforation side of the tape • Qty 5 kpcs/reel

Remark To order evaluation samples, please contact your nearby sales office.
Part number for sample order: μPG2406T6R-A

Caution Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions must be employed at all times.

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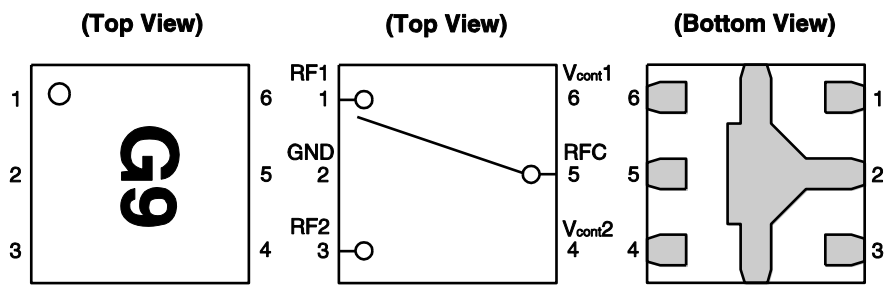
PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Pin No.	Pin Name
1	RF1
2	GND
3	RF2
4	$V_{cont}2$
5	RFC
6	$V_{cont}1$

SW TRUTH TABLE

ON Path	$V_{cont}1$	$V_{cont}2$
RFC-RF1	High	Low
RFC-RF2	Low	High

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Switch Control Voltage		V_{cont}	+6.0 Note	V
Input Power	f = 0.01 to 0.5 GHz	$P_{in}1$	+24.0	dBm
	f = 0.5 to 3.0 GHz	$P_{in}2$	+31.0	
Operating Ambient Temperature		T_A	−45 to +85	°C
Storage Temperature		T_{stg}	−55 to +150	°C

Note $|V_{cont}1 - V_{cont}2| \leq 6.0$ V

RECOMMENDED OPERATING RANGE (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Switch Control Voltage (H)	$V_{cont\ (H)}$	1.8	2.7	3.3	V
Switch Control Voltage (L)	$V_{cont\ (L)}$	−0.2	0	0.2	V
Control Voltage Difference	$\Delta V_{cont\ (H)}$, $\Delta V_{cont\ (L)}$ Note	−0.1	0	0.1	V

Note $\Delta V_{cont\ (H)} = V_{cont}1_{\ (H)} - V_{cont}2_{\ (H)}$

$\Delta V_{cont\ (L)} = V_{cont}1_{\ (L)} - V_{cont}2_{\ (L)}$

ELECTRICAL CHARACTERISTICS

(T_A = +25°C, $V_{cont\ (H)}$ = 2.7 V, $V_{cont\ (L)}$ = 0 V, DC blocking capacitors = 56 pF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss 1	$L_{ins}1$	f = 0.01 to 0.05 GHz Note 1	–	0.40	–	dB
Insertion Loss 2	$L_{ins}2$	f = 0.05 to 0.5 GHz Note 2	–	0.40	0.45	dB
Insertion Loss 3	$L_{ins}3$	f = 0.5 to 1.0 GHz	–	0.40	0.45	dB
Insertion Loss 4	$L_{ins}4$	f = 1.0 to 2.0 GHz	–	0.45	0.50	dB
Insertion Loss 5	$L_{ins}5$	f = 2.0 to 2.5 GHz	–	0.47	0.55	dB
Insertion Loss 6	$L_{ins}6$	f = 2.5 to 3.0 GHz	–	0.53	0.60	dB
Isolation 1	ISL1	f = 0.01 to 0.05 GHz Note 1	–	27	–	dB
Isolation 2	ISL2	f = 0.05 to 0.5 GHz Note 2	23	27	–	dB
Isolation 3	ISL3	f = 0.5 to 1.0 GHz	23	27	–	dB
Isolation 4	ISL4	f = 1.0 to 2.0 GHz	16	19	–	dB
Isolation 5	ISL5	f = 2.0 to 2.5 GHz	14	17	–	dB
Isolation 6	ISL6	f = 2.5 to 3.0 GHz	14	17	–	dB
Input Return Loss 1	$RL_{in}1$	f = 0.01 to 0.05 GHz Note 1	–	20	–	dB
Input Return Loss 2	$RL_{in}2$	f = 0.05 to 0.5 GHz Note 2	15	20	–	dB
Input Return Loss 3	$RL_{in}3$	f = 0.5 to 3.0 GHz	15	20	–	dB
Output Return Loss 1	$RL_{out}1$	f = 0.01 to 0.05 GHz Note 1	–	20	–	dB
Output Return Loss 2	$RL_{out}2$	f = 0.05 to 0.5 GHz Note 2	15	20	–	dB
Output Return Loss 3	$RL_{out}3$	f = 0.5 to 3.0 GHz	15	20	–	dB
0.1 dB Loss Compression Input Power Note 3	$P_{in\ (0.1\ dB)}$	f = 2.0/2.5 GHz	+26.0	+29.0	–	dBm
		f = 0.5 to 3.0 GHz	–	+29.0	–	dBm
1 dB Loss Compression Input Power Note 4	$P_{in\ (1\ dB)}$	f = 0.5 to 3.0 GHz	–	+30.5	–	dBm
2nd Harmonics	$2f_0$	f = 2.0/2.5 GHz, P_{in} = +20 dBm	65	75	–	dBc
3rd Harmonics	$3f_0$	f = 2.0/2.5 GHz, P_{in} = +20 dBm	65	75	–	dBc
Intermodulation Intercept Point	IIP_3	f = 0.5 to 3.0 GHz, 2 tone, 5 MHz spicing	–	+60	–	dBm
Switch Control Current	I_{cont}	No RF input	–	0.2	20	μA
Switch Control Speed	t_{SW}	50% CTL to 90/10% RF	–	50	500	ns

Notes 1. DC blocking capacitors = 10 000 pF at f = 0.01 to 0.05 GHz

2. DC blocking capacitors = 1 000 pF at f = 0.05 to 0.5 GHz

3. $P_{in\ (0.1\ dB)}$ is measured the input power level when the insertion loss increases more 0.1 dB than that of linear range.

4. $P_{in\ (1\ dB)}$ is measured the input power level when the insertion loss increases more 1 dB than that of linear range.

Caution This device is used it is necessary to use DC blocking capacitors.
The value of DC blocking capacitors should be chosen to accommodate the frequency of operation, bandwidth, switching speed and the condition with actual board of your system. The range of recommended DC blocking capacitor value is less than 56 pF.

ELECTRICAL CHARACTERISTICS

(T_A = +25°C, $V_{cont\ (H)}$ = 1.8 V, $V_{cont\ (L)}$ = 0 V, DC blocking capacitors = 56 pF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss 7	$L_{ins}7$	f = 0.01 to 0.05 GHz Note 1	–	0.40	–	dB
Insertion Loss 8	$L_{ins}8$	f = 0.05 to 0.5 GHz Note 2	–	0.40	0.46	dB
Insertion Loss 9	$L_{ins}9$	f = 0.5 to 1.0 GHz	–	0.40	0.47	dB
Insertion Loss 10	$L_{ins}10$	f = 1.0 to 2.0 GHz	–	0.46	0.52	dB
Insertion Loss 11	$L_{ins}11$	f = 2.0 to 2.5 GHz	–	0.48	0.57	dB
Insertion Loss 12	$L_{ins}12$	f = 2.5 to 3.0 GHz	–	0.54	0.62	dB
Isolation 7	ISL7	f = 0.01 to 0.05 GHz Note 1	–	27	–	dB
Isolation 8	ISL8	f = 0.05 to 0.5 GHz Note 2	23	27	–	dB
Isolation 9	ISL9	f = 0.5 to 1.0 GHz	23	27	–	dB
Isolation 10	ISL10	f = 1.0 to 2.0 GHz	16	19	–	dB
Isolation 11	ISL11	f = 2.0 to 2.5 GHz	14	17	–	dB
Isolation 12	ISL12	f = 2.5 to 3.0 GHz	14	17	–	dB
Input Return Loss 4	$RL_{in}4$	f = 0.01 to 0.05 GHz Note 1	–	20	–	dB
Input Return Loss 5	$RL_{in}5$	f = 0.05 to 0.5 GHz Note 2	15	20	–	dB
Input Return Loss 6	$RL_{in}6$	f = 0.5 to 3.0 GHz	15	20	–	dB
Output Return Loss 4	$RL_{out}4$	f = 0.01 to 0.05 GHz Note 1	–	20	–	dB
Output Return Loss 5	$RL_{out}5$	f = 0.05 to 0.5 GHz Note 2	15	20	–	dB
Output Return Loss 6	$RL_{out}6$	f = 0.5 to 3.0 GHz	15	20	–	dB
0.1 dB Loss Compression Input Power Note 3	$P_{in\ (0.1\ dB)}$	f = 2.0/2.5 GHz	+19.0	+22.0	–	dBm
		f = 0.5 to 3.0 GHz	–	+22.0	–	dBm
1 dB Loss Compression Input Power Note 4	$P_{in\ (1\ dB)}$	f = 0.5 to 3.0 GHz	–	+25.0	–	dBm
Switch Control Current	I_{cont}	No RF input	–	0.2	20	μA
Switch Control Speed	tsw	50% CTL to 90/10% RF	–	50	500	ns

Notes 1. DC blocking capacitors = 10 000 pF at f = 0.01 to 0.05 GHz

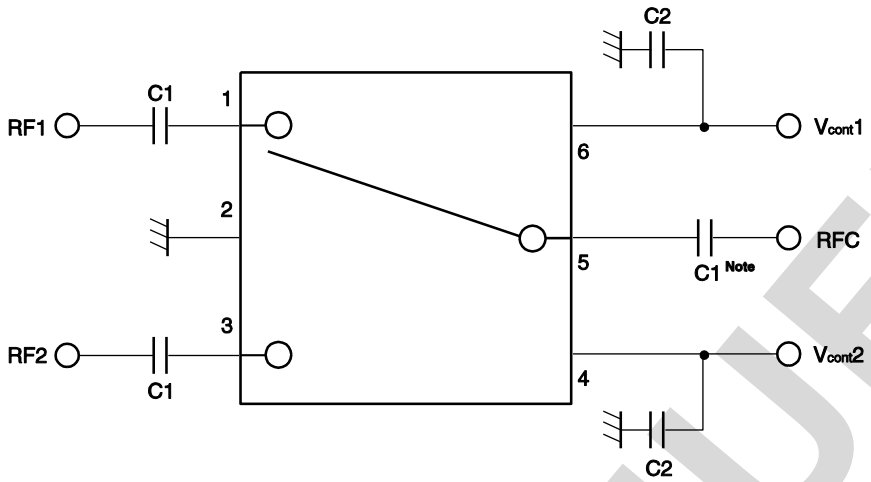
2. DC blocking capacitors = 1 000 pF at f = 0.05 to 0.5 GHz

3. $P_{in\ (0.1\ dB)}$ is measured the input power level when the insertion loss increases more 0.1 dB than that of linear range.

4. $P_{in\ (1\ dB)}$ is measured the input power level when the insertion loss increases more 1 dB than that of linear range.

Caution This device is used it is necessary to use DC blocking capacitors.
The value of DC blocking capacitors should be chosen to accommodate the frequency of operation, bandwidth, switching speed and the condition with actual board of your system. The range of recommended DC blocking capacitor value is less than 56 pF.

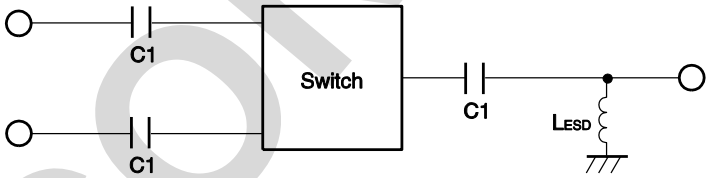
EVALUATION CIRCUIT



Note C1 : 0.01 to 0.05 GHz 10 000 pF
: 0.05 to 0.5 GHz 1 000 pF
: 0.5 to 3.0 GHz 56 pF
C2 : 1 000 pF

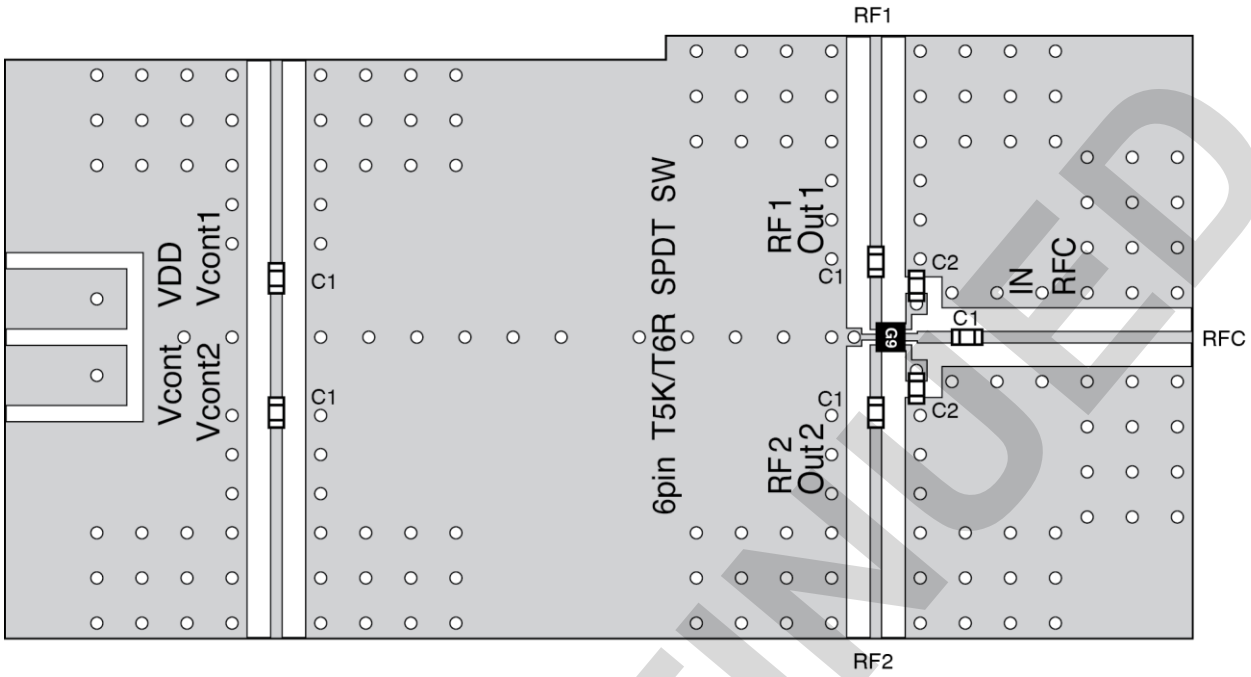
The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

APPLICATION INFORMATION



- L_{ESD} provides a means to increase the ESD protection on a specific RF port, typically the port attached to the antenna.
- The value may be tailored to provide specific electrical responses.
- The RF ground connections should be kept as short as possible and connected to directly to a good RF ground for best performance.

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD

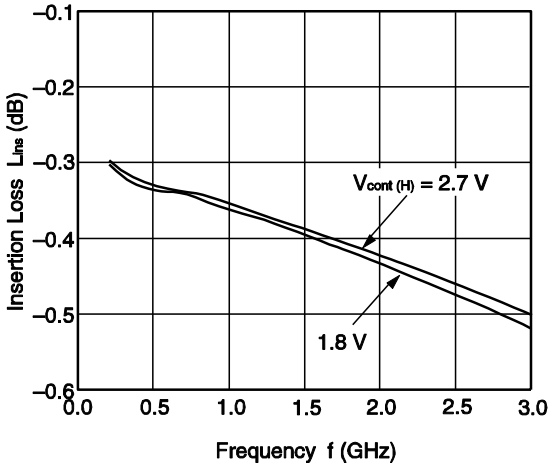


USING THE EVALUATION BOARD

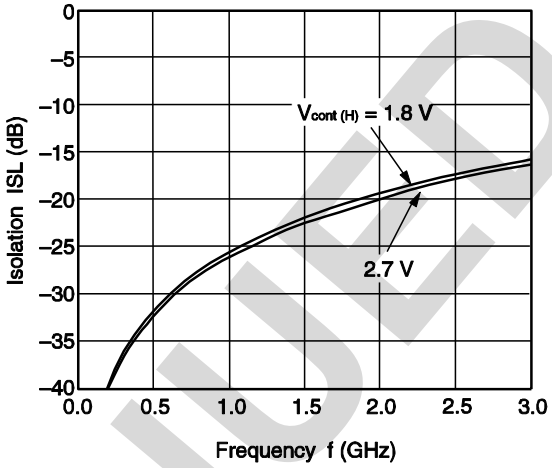
Symbol	Test Conditions	Values
C1	f = 0.01 to 0.05 GHz	10 000 pF
	f = 0.05 to 0.5 GHz	1 000 pF
	f = 0.5 to 3.0 GHz	56 pF
C2		1 000 pF

TYPICAL CHARACTERISTICS (T_A = +25°C, DC blocking capacitors = 56 pF, unless otherwise specified)

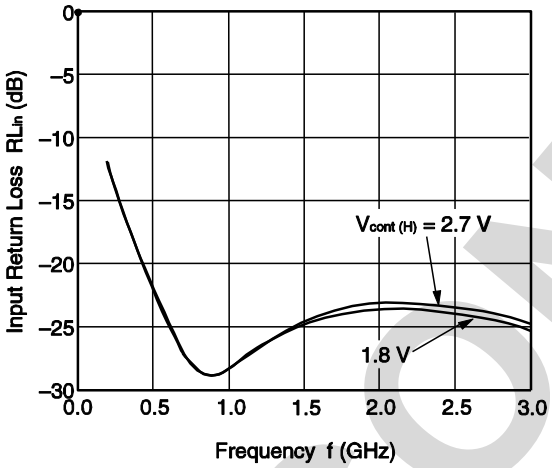
RFC-RF1/RF2
INSERTION LOSS vs. FREQUENCY



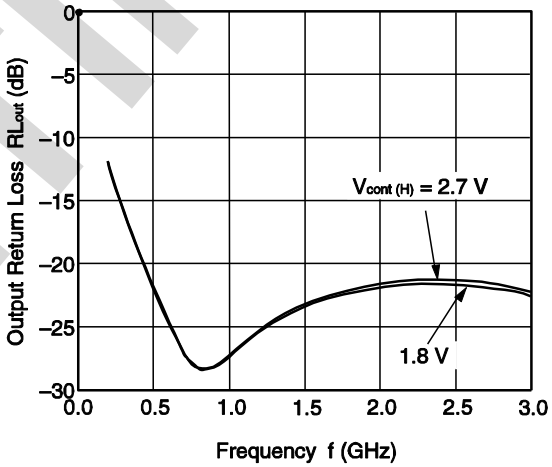
RFC-RF1/RF2
ISOLATION vs. FREQUENCY



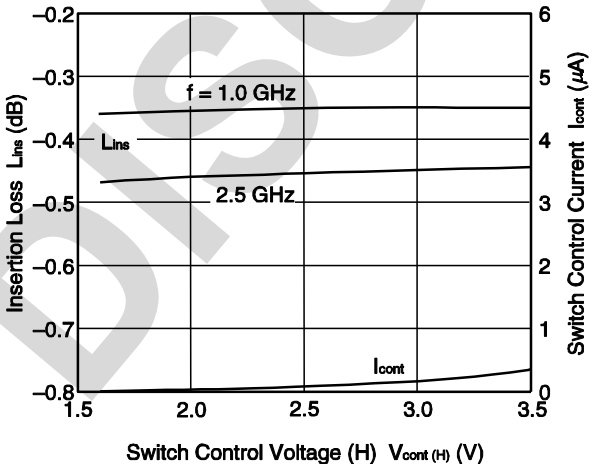
RFC-RF1/RF2
INPUT RETURN LOSS vs. FREQUENCY



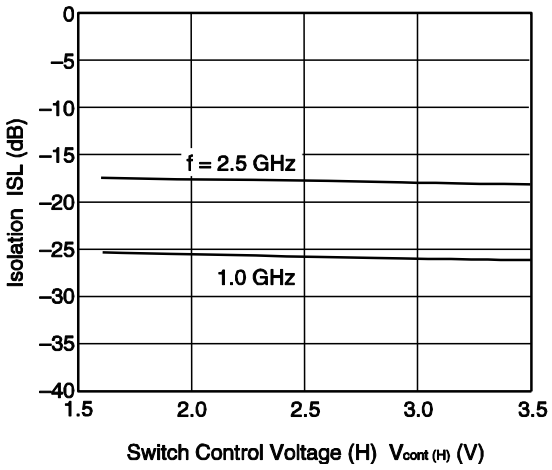
RFC-RF1/RF2
OUTPUT RETURN LOSS vs. FREQUENCY



RFC-RF1/RF2 INSERTION LOSS,
I_{cont} vs. SWITCH CONTROL VOLTAGE (H)

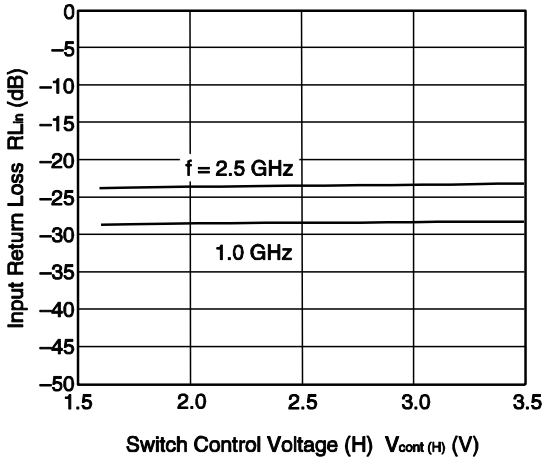


RFC-RF1/RF2 ISOLATION vs.
SWITCH CONTROL VOLTAGE (H)

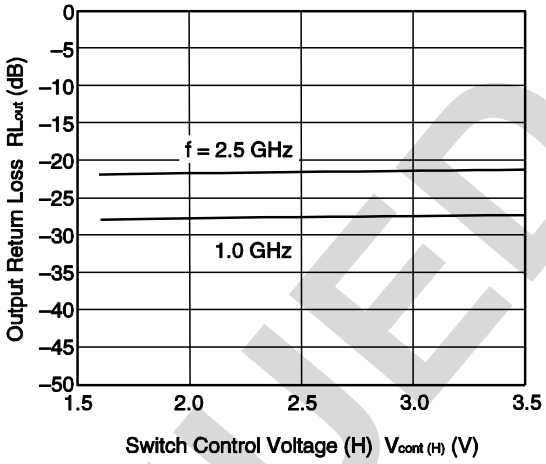


Remark The graphs indicate nominal characteristics.

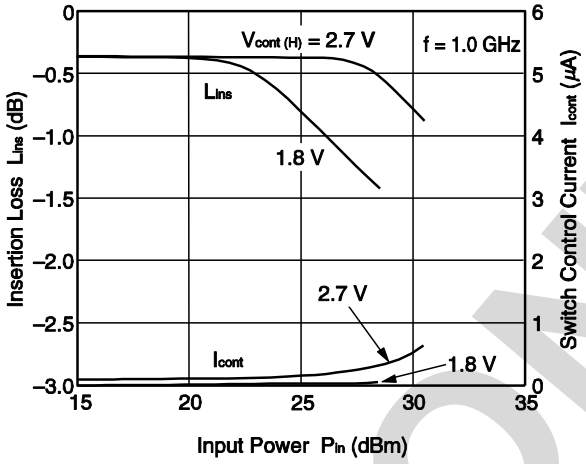
RFC-RF1/RF2 INPUT RETURN LOSS vs. SWITCH CONTROL VOLTAGE (H)



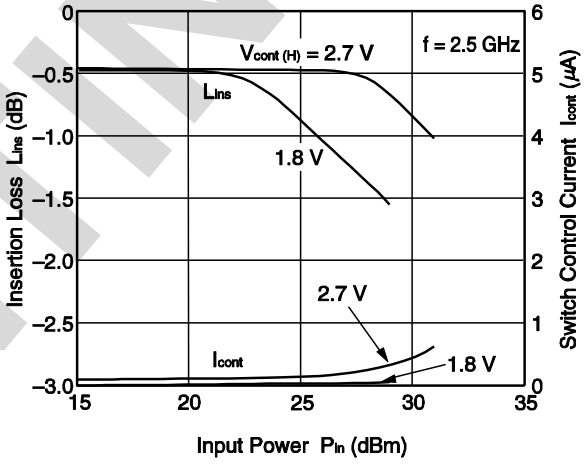
RFC-RF1/RF2 OUTPUT RETURN LOSS vs. SWITCH CONTROL VOLTAGE (H)



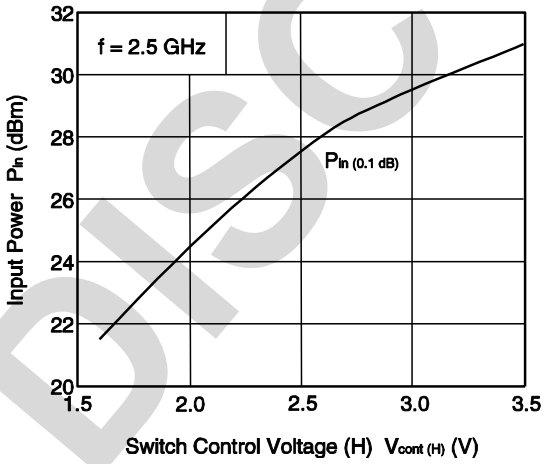
RFC-RF1/RF2 INSERTION LOSS, Icont vs. INPUT POWER



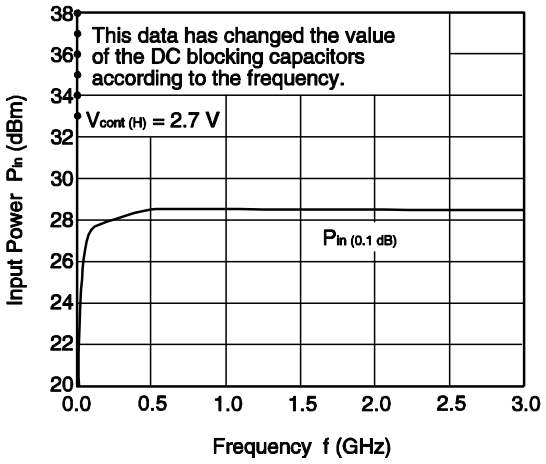
RFC-RF1/RF2 INSERTION LOSS, Icont vs. INPUT POWER



RFC-RF1/RF2 INPUT POWER vs. SWITCH CONTROL VOLTAGE (H)



RFC-RF1/RF2 INPUT POWER vs. FREQUENCY

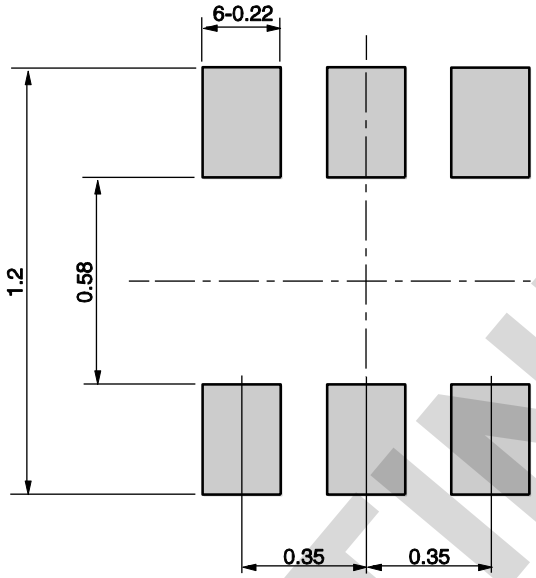


Remark The graphs indicate nominal characteristics.

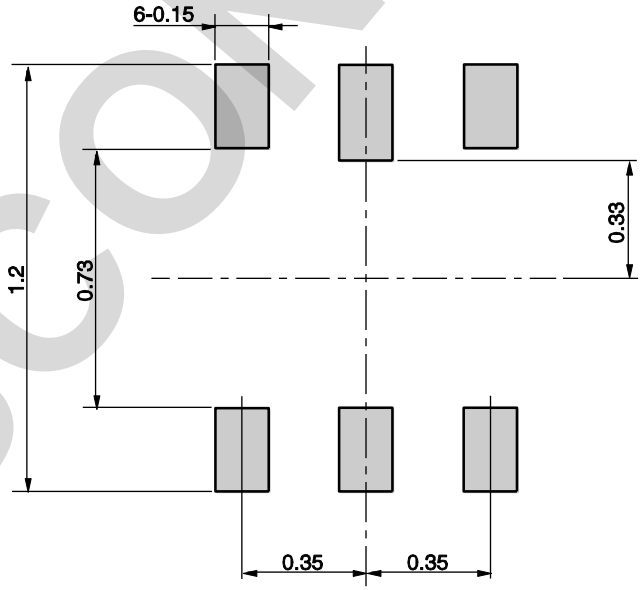
MOUNTING PAD AND SOLDER MASK LAYOUT DIMENSIONS

6-PIN PLASTIC TSSON (T6R) (UNIT: mm)

MOUNTING PAD



SOLDER MASK

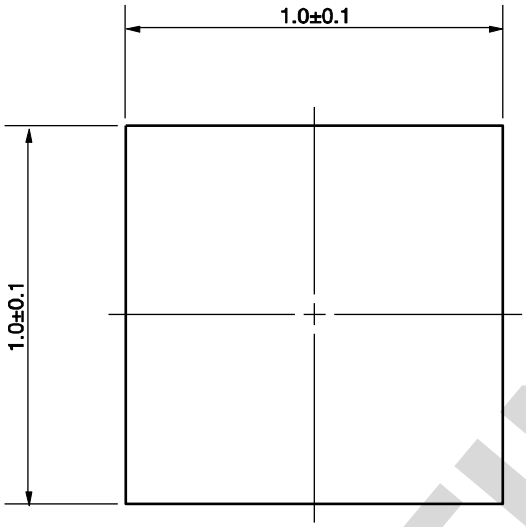


Remark The mounting pad and solder mask layouts in this document is for reference only.
When designing PCB, please consider workability of mounting, solder joint reliability, prevention of solder bridge and so on, in order to optimize the design.

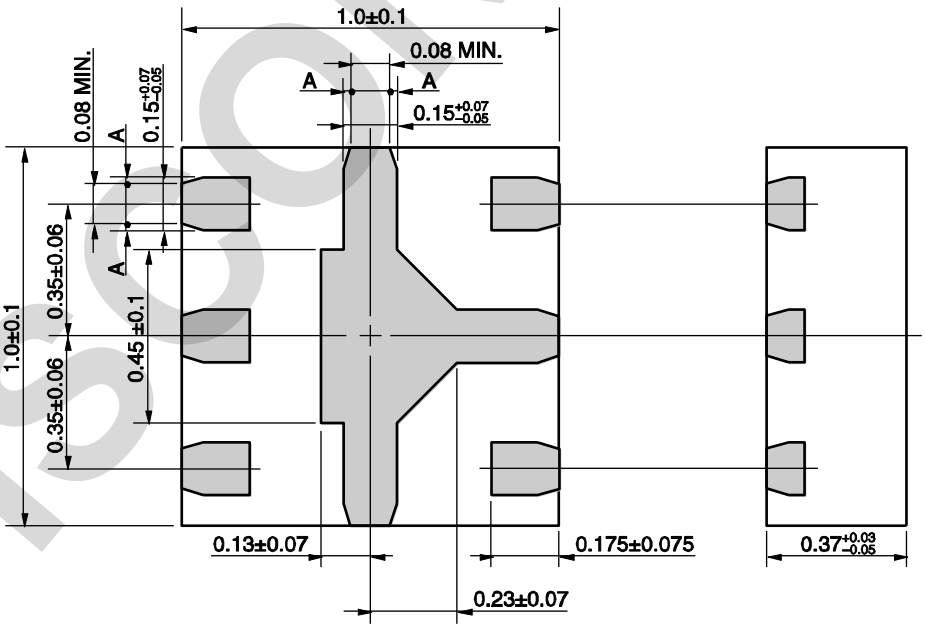
PACKAGE DIMENSIONS

6-PIN PLASTIC TSSON (T6R) (UNIT: mm)

(Top View)



(Bottom View)



Remark A > 0

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	: 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Partial Heating	Peak temperature (terminal temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	

Caution Do not use different soldering methods together (except for partial heating).

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points. • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.